

**AMENDMENTS TO THE CLAIMS:**

1. (Cancelled)

2. (Currently Amended) The high frequency switch as defined in Claim [[1]] 8, wherein  
~~said sharing device a high frequency filter configured by capacitive coupling is provided at an the~~  
end of said reception port is configured by capacitive coupling.

3. (Cancelled)

4. (Currently Amended) The high frequency switch as defined in Claim 2, wherein said  
~~high frequency filter is a sharing device made by combining two SAW filters is a high frequency~~  
filter.

5. (Cancelled)

6. (Currently Amended) The high frequency switch as defined in Claim [[5]] 8, wherein  
an LC filter is connected to an end of said transmission port, said LC filter being formed in an  
inner layer of said multilayer board.

7. (Cancelled)

8. (Currently Amended) A high frequency switch comprising:

a first FET switch connected between an input and output (I/O) port and a transmission port;

a strip line connected between said I/O port and a reception port, said strip line having an electrical length equivalent to 1/4 wavelength of a high frequency signal input from said transmission port;

a second FET switch whose one end is connected to said strip line and to a side of said reception port and the other end is ground; and

a control port for controlling turning on and off of said first and second FET switches;

wherein said strip line is formed in an inner layer of a dielectric multilayer board,

wherein said first and second FET switches are mounted on a surface of said multilayer board as a high frequency device, and

The high frequency switch as defined in Claim 5, wherein a sharing device made by combining two SAW filters is connected to an end of said reception port, said sharing device being mounted on the surface of said multilayer board.